

Date: - 20th March, 2014

Data Sheet Issue:- 2

# Rectifier Diode Types W1748LC180 to W1748LC250

Previous Type No.: SW02-22CXC805

#### **Absolute Maximum Ratings**

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage, (note 1)	1800-2500	V
V <sub>RSM</sub>	Non-repetitive peak reverse voltage, (note 1)	1900-2600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I <sub>F(AV)M</sub>	Maximum average forward current, T <sub>sink</sub> =55°C, (note 2)	1748	А
I <sub>F(AV)M</sub>	Maximum average forward current. T <sub>sink</sub> =100°C, (note 2)	1288	А
I <sub>F(RMS)M</sub>	Nominal RMS forward current, T <sub>sink</sub> =25°C, (note 2)	3157	Α
I <sub>F(d.c.)</sub>	D.C. forward current, T <sub>sink</sub> =25°C, (note 3)	2371	А
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> =60%V <sub>RRM</sub> , (note 4)	15.4	kA
I <sub>FSM2</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 4)	17.7	kA
l <sup>2</sup> t	I <sup>2</sup> t capacity for fusing t <sub>p</sub> =10ms, V <sub>rm</sub> =60%V <sub>RRM</sub> , (note 4)	1.18×10 <sup>6</sup>	A <sup>2</sup> s
l <sup>2</sup> t	I²t capacity for fusing t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 4)	1.56×10 <sup>6</sup>	A <sup>2</sup> s
T <sub>j op</sub>	Operating temperature range	-40 to +175	°C
T <sub>stg</sub>	Storage temperature range	-40 to +200	°C

#### Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T<sub>j</sub> below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Double side cooled.
- 4) Half-sinewave, 175°C T<sub>j</sub> initial.



# **Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
$V_{FM}$	Maximum peak forward voltage	-	-	1.93	I <sub>FM</sub> =3770A	V
V <sub>T0</sub>	Threshold voltage	-	-	0.87		V
r⊤	Slope resistance	-	-	0.28		mΩ
I <sub>RRM</sub>	Peak reverse current	-	-	30	Rated V <sub>RRM</sub>	mA
Б	The survey was interest in wasting to be attainly	-	-	0.033	Double side cooled	K/W
R <sub>thJK</sub>	Thermal resistance, junction to heatsink	-	-	0.065	Single side cooled	K/W
F	Mounting force	10	-	20	Note 2	kN
$W_t$	Weight		340			g

## Notes:-

- Unless otherwise indicated T<sub>j</sub>=175°C.
   For other clamp forces, please consult factory.



### **Notes on Ratings and Characteristics**

## 1.0 Voltage Grade Table

Voltage Grade	V <sub>RRM</sub> V	V <sub>RSM</sub> V	V <sub>R</sub> DC V
18	1800	1900	1150
22	2200	2300	1350
25	2500	2600	1500

## 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

#### 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T<sub>i</sub> below 25°C.

#### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

### 5.0 Computer Modelling Parameters

## 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \qquad \qquad W_{AV} = \frac{\Delta T}{R_{th}} \qquad \qquad \Delta T = T_{j \max} - T_K$$

Where  $V_{T0}=0.87V$ ,  $r_{T}=0.28m\Omega$ ,

 $R_{th}$  = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°)					
Square wave Double Side Cooled	0.0455	0.0393	0.0362	0.0319	
Square wave Cathode Side Cooled	0.0753	0.0711	0.0687	0.0646	
Sine wave Double Side Cooled	0.0397	0.0350	0.0313		
Sine wave Cathode Side Cooled	0.0699	0.0677	0.0653		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



## 5.2 Calculating V<sub>F</sub> using ABCD Coefficients

The on-state characteristic I<sub>F</sub> vs. V<sub>F</sub>, on page 8 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for  $V_F$  in terms of  $I_F$  given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for characteristics at the maximum junction temperature of 175°C. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

175°C Coefficients					
Α	0.3867852				
В	0.05612815				
С	0.240698×10 <sup>-3</sup>				
D	2.821743×10-3				



## 5.3 D.C. Thermal Impedance Calculation

$$r_{t} = \sum_{p=1}^{p=n} r_{p} \cdot \left(1 - e^{\frac{-t}{\tau_{p}}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 $r_{t}$  = Thermal resistance at time t.

 $r_p$  = Amplitude of  $p_{th}$  term.

 $\tau_p$  = Time Constant of  $r_{th}$  term.

The coefficients for this device are shown in the tables below:

	D.C. Double Side Cooled						
Term	1 2 3 4						
$r_p$	0.017719	4.2406×10 <sup>-3</sup>	6.9638×10 <sup>-3</sup>	3.04366×10 <sup>-3</sup>			
$ au_{\mathcal{P}}$	0.708578	0.1435833	0.036152	2.1308×10 <sup>-3</sup>			

	D.C. Single Side Cooled						
Term	1	2	3	4	5		
$r_{\rho}$	0.04013	6.3388×10 <sup>-3</sup>	0.011408	6.0275×10 <sup>-3</sup>	7.2098×10 <sup>-4</sup>		
$ au_{\mathcal{P}}$	4.07311	2.15774	0.19931	9.0689×10 <sup>-3</sup>	4.66345×10 <sup>-4</sup>		



#### **Curves**

Figure 1 – Mean forward current vs. power dissipation– Double side cooled

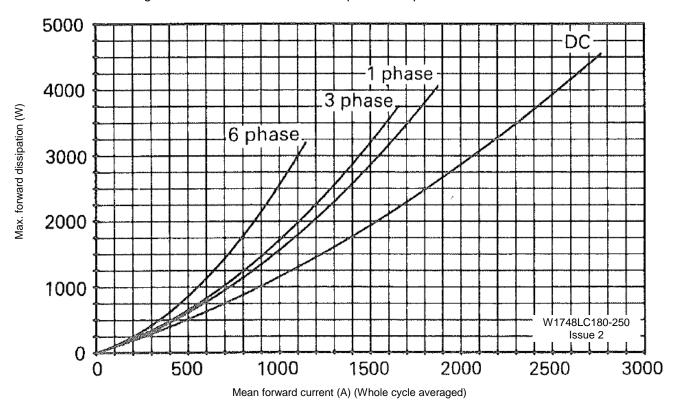


Figure 2 - Mean forward current vs. power dissipation - Single side cooled

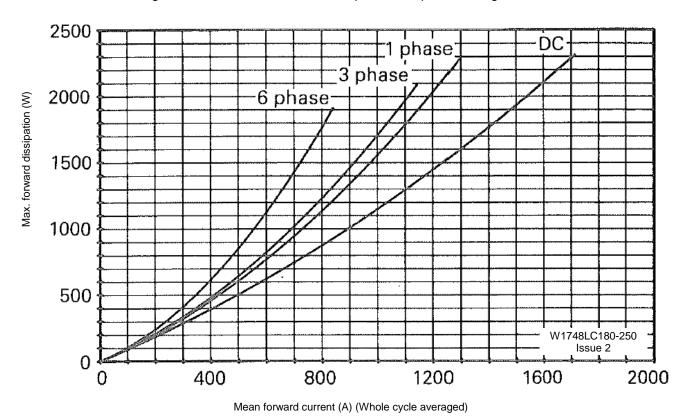
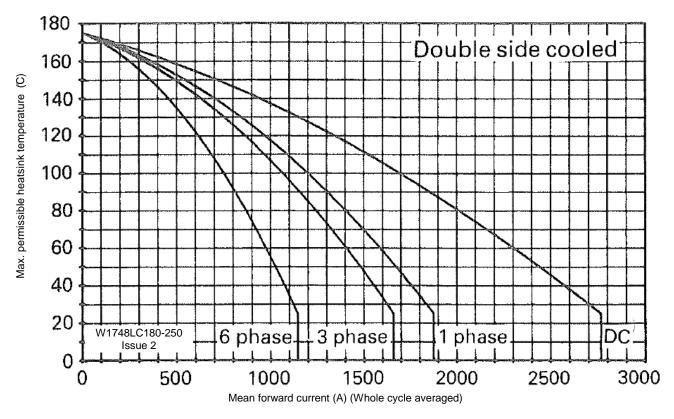
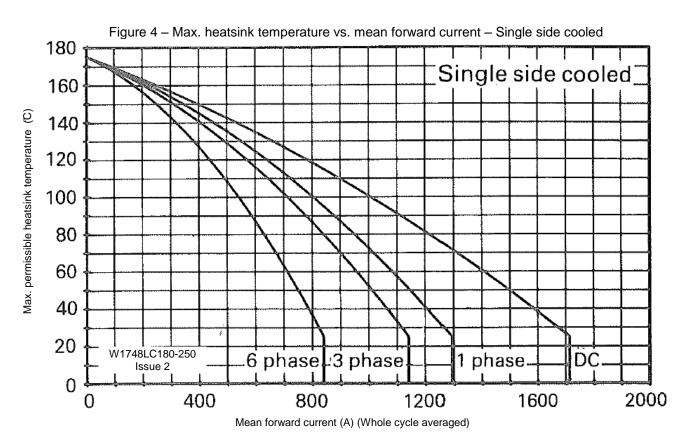




Figure 3 – Max. heatsink temperature vs. mean forward current – Double side cooled







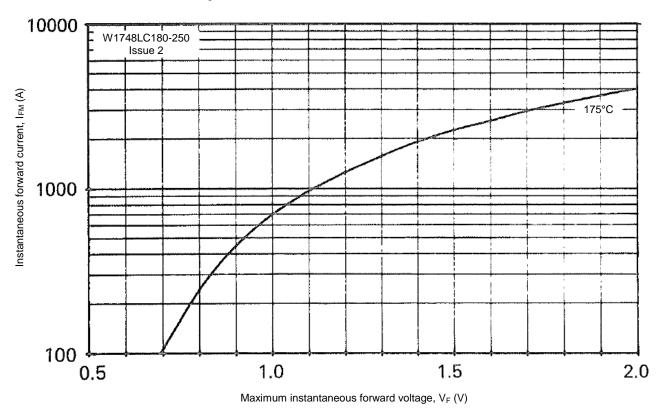
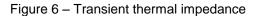


Figure 5 – Forward characteristics of limit device



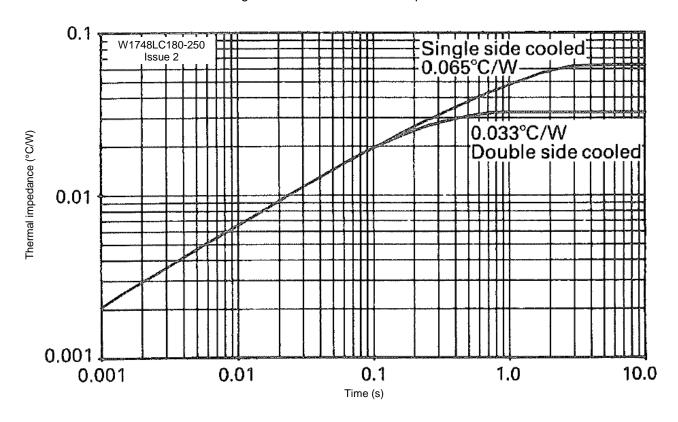
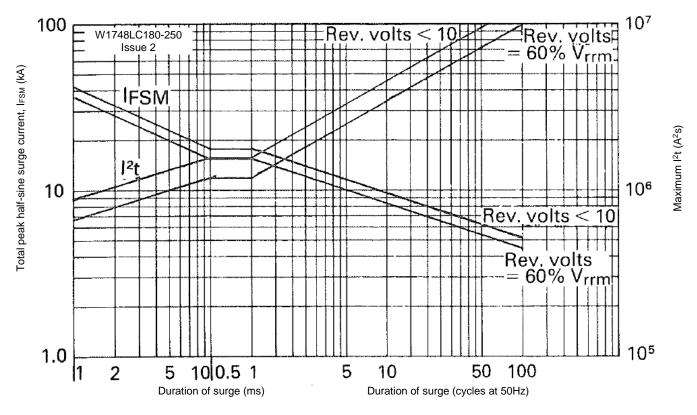


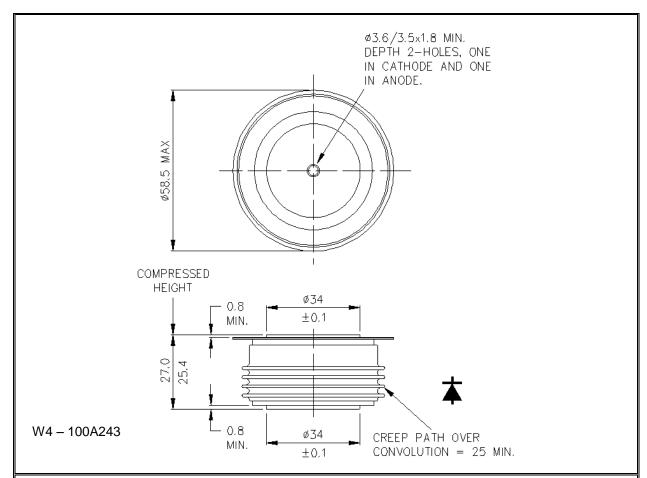


Figure 7 – Maximum non-repetitive surge current at initial junction temperature 160°C





## **Outline Drawing & Ordering Information**



#### ORDERING INFORMATION

(Please quote 10 digit code as below)

		` '	<u> </u>
W1748	LC	<b>**</b>	0
Fixed Type Code	Fixed Outline Code	Voltage code V <sub>RRM</sub> /100 18-25	Fixed code

Order code: W1748LC250 – 2500V  $V_{RRM}$ , 27mm clamp height capsule.

#### **IXYS Semiconductor GmbH**

Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627 E-mail: marcom@ixys.de



## IXYS UK Westcode Ltd

Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448 E-mail: sales@ixysuk.com

#### **IXYS Corporation**

1590 Buckeye Drive Milpitas CA 95035-7418 Tel: +1 (408) 457 9000 Fax: +1 (408) 496 0670 E-mail: sales@ixys.net

# www.ixysuk.com

www.ixys.com

#### **IXYS Long Beach**

IXYS Long Beach, Inc 2500 Mira Mar Ave, Long Beach CA 90815 Tel: +1 (562) 296 6584 Fax: +1 (562) 296 6585

E-mail: service@ixyslongbeach.com

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